

# TIGER ELECTRONIC CO.,LTD 1N4728 THRU 1N4764

**1W SILICON PLANAR ZENER DIODES** 

DO-41(GLASS)

#### **FEATURES**

- . Silicon planar power zener diodes
- For use in stabilizing and clipping circuits with high power rating.
- . Standaards Zener voltage toerance is± 10%

Add suffix"A" for  $\pm~5\%$  tolerance Other tolerance available upon request

## 

Dimensions in inches and (millimeters)

### **MECHANICAL DATA**

. **Case:** DO-41 glass case .weight: Approx. 0.35 gram

### ABSOLUTE MAXIMUM RATINGS(LIMITING VALUES)(TA=25°C)

	Symbols	Value	Units
Zener current see table "Characteristics"			
Power dissipation at TA=25°C	Ptot	1 1)	mW
Junction temperature	TJ	175	$^{\circ}$
Storage temperature range	Тѕтс	-65 to +175	$^{\circ}$

#### **ELECTRCAL CHARACTERISTICS**(TA=25°C)

	Symbols	Min	Тур	Max	Units			
Thermal resistance junction to ambient	RthA			170 1)	°C/W			
Forward voltage at IF=200mA	VF			1.2	V			
Valid provided that a distance at 8mm from case are kept at ambient temperature								



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#### 1N4728..1N4764 SILICON PLANAR ZENER DIODES

Typo	Nominal Zener	Test Current	Maximum Zener Impedance 1)			Maximum reverse leakage current		Surge current	Maximum regulator	
Type	Voltage 3)		ot .		at .			at T <sub>A</sub> =0.25	Current 2)	
	at !		at	7	at		-+\/-		1784	
	Izt V= V	I A	Izт <b>7-</b> - О	Zzĸ	Izk	Ι_ 11 Λ	at V <sub>R</sub> V	IR m ^	IZM ~~ ^	
4114700	Vz V	Izt mA	Z <sub>ZT</sub> Ω	Ω	mA	IRμA		mA	mA	
1N4728	3.3	76	10	400		100 50	1.0	1380	276	
1N4729	3.6	69	10		0		1.0	1260	252	
1N4730	3.9	64	9				1.0	1190	234	
1N4731	4.3	58	9	F00	1.0		1.0	1070	217	
1N4732	4.7	53	8	500			1.0	970	193	
1N4733	5.1	49	7	550			1.0	890	178	
1N4734	5.6	45	5	600			2.0	810	162	
1N4735	6.2	41	2				3.0	730	146	
1N4736	6.8	37	3.5				4.0	660	133	
1N4737	7.5	34	4.0				5.0	605	121	
1N4738	8.2	31	4.5		5.0		6.0	550	110	
1N4739	9.1	28	5.0				7.0	500	100	
1N4740	10	25	7	700			7.6	454	91	
1N4741	11	23	8					8.4	414	83
1N4742	12	21	9				9.1	380	76	
1N4743	13	19	10				9.9	344	69	
1N4744	15	17	14				11.4	304	61	
1N4745	16	15.5	16		0.25		12.2	285	57	
1N4746	18	14	20	750		5	13.7	250	50	
1N4747	20	12.5	22				15.2	225	45	
1N4748	22	11.5	23				16.7	205	41	
1N4749	24	10.5	25				18.2	190	38	
1N4750	27	9.5	35				20.6	170	34	
1N4751	30	8.5	40	1000			22.8	150	30	
1N4752	33	7.5	45				25.1	135	27	
1N4753	36	7.0	50				27.4	125	25	
1N4754	39	6.5	60				29.7	115	23	
1N4755	43	6.0	70	1500			32.7	110	22	
1N4756	47	5.5	80				35.8	95	19	
1N4757	51	5.0	95				38.8	90	18	
1N4758	56	4.5	110				42.6	80	16	
1N4759	62	4.0	125	2000			47.1	70	14	
1N4760	68	3.7	150	2000			51.7	65	13	
1N4761	75	3.3	175				56.0	60	12	
1N4762	82	3.0	200				62.2	55	11	
1N4763	91	2.8	250	3000			69.2	50	10	
1N4764	100	2.5	350				76.0	45	9	

Notes:1) The Zener impedance is derived from the 1KHz AC voltage which results when an AC current having an RMS calue equal to 10% of the Zener current(IZT or IZK) is superimposed on IZT or IZK. Zener impedance is measured at two points to insure a sharp knee on the breakdown curve and to eliminate unstable units.

<sup>2)</sup>Valid provided that electrodes at a distance of 10mm from case are kept at ambient temperature

<sup>3)</sup>Measured under thermal equilibriun and DC test conditions.



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### **RATINGS AND CHARACTERISTIC CURVES 1N4728 THRI 1N4764**

Admissible power dissipation versus ambient temperature (Valid provided that leads at a distance of 10mm from case are kept at ambient temperature)

